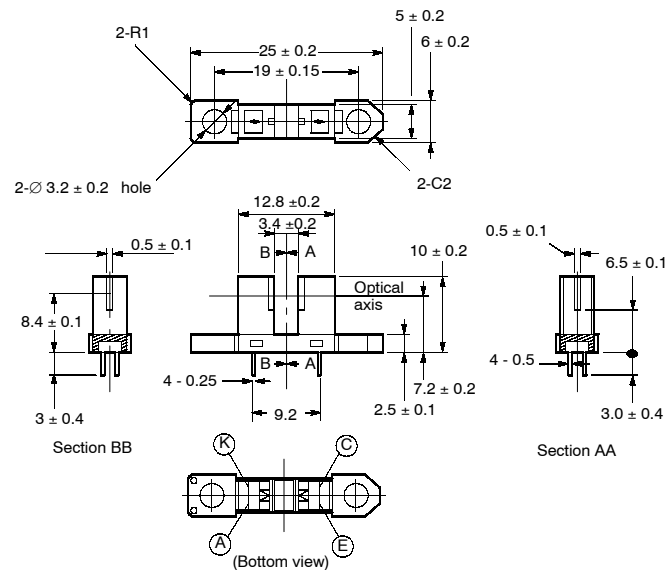


# OMRON EE-SX2088

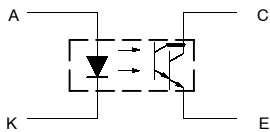
# Photomicrosensor (Transmissive)

## ■ Dimensions

**Note:** All units are in millimeters unless otherwise indicated.



### Internal Circuit



Unless otherwise specified, the tolerances are  $\pm 0.2$  mm.

Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

## ■ Features

- 0.5-mA output min. with only 1-mA forward LED current.
- Mounting tabs to secure EE-SX2088 to PCB.
- Best suited to drive CMOS IC.

## ■ Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Item		Symbol	Rated value
Emitter	Forward current	$I_F$	50 mA (see note 1)
	Pulse forward current	$I_{FP}$	1 A (see note 2)
	Reverse voltage	$V_R$	4 V
Detector	Collector-Emitter voltage	$V_{CEO}$	35 V
	Emitter-Collector voltage	$V_{ECO}$	---
	Collector current	$I_C$	20 mA
	Collector dissipation	$P_C$	100 mW (see note 1)
Ambient temperature	Operating	$T_{opr}$	$-25^\circ\text{C}$ to $85^\circ\text{C}$
	Storage	$T_{stg}$	$-30^\circ\text{C}$ to $100^\circ\text{C}$

- Note:**
1. Refer to the temperature rating chart if the ambient temperature exceeds  $25^\circ\text{C}$ .
  2. The pulse width is 10  $\mu\text{s}$  maximum with a frequency of 100 Hz.
  3. Complete soldering within 10 seconds.

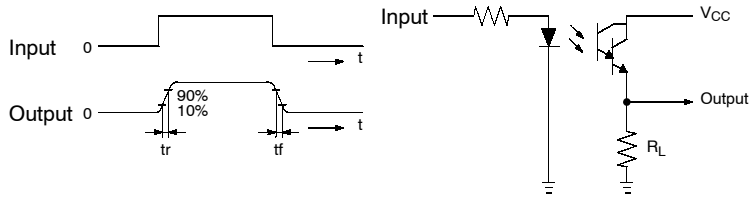
## ■ Ordering Information

Description	Part number
Photomicrosensor (Transmissive)	EE-SX2088

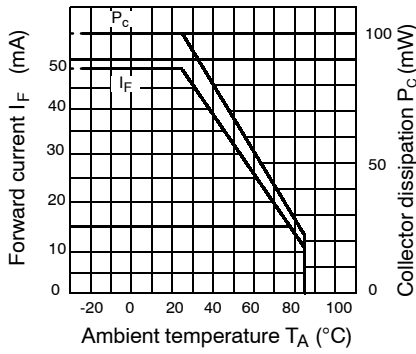
## ■ Electrical and Optical Characteristics ( $T_a = 25^\circ\text{C}$ )

Item		Symbol	Value	Condition
Emitter	Forward voltage	$V_F$	1.2 V typ.; 1.4 V max.	$I_F = 20\text{mA}$
	Reverse current	$I_R$	0.01 $\mu\text{A}$ typ.; 10 $\mu\text{A}$ max.	$V_R = 4\text{V}$
	Peak emission wavelength	$\lambda_p(L)$	940 nm typ.	$I_F = 20\text{mA}$
Detector	Dark current	$I_D$	2 nA typ.; 1000 nA max.	$V_{CE} = 10\text{V } 0\text{ Hz}$
	Peak spectral sensitivity wavelength	$\lambda_p(P)$	850 nm typ.	$V_{CE} = 5\text{V}$
Combination	Light current (collector current)	$I_L$	0.5 to 20 mA	$I_F = 1\text{mA}$ $V_{CE} = 2\text{V}$
	Collector-emitter saturated voltage	$V_{CE}(\text{sat})$	0.75 V typ.; 1 V max.	$I_F = 2\text{mA}$ $I_L = 0.5\text{mA}$
	Rising time*	$t_r$	70 $\mu\text{s}$ typ.	$V_{CC} = 2\text{V}$ $I_L = 2\text{mA}$
	Falling time*	$t_f$	70 $\mu\text{s}$ typ.	$R_L = 100\ \Omega$

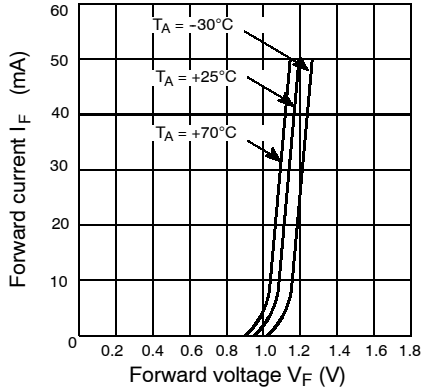
\*The illustrations on the following page show the rising time,  $t_r$ , and the falling time,  $t_f$ .



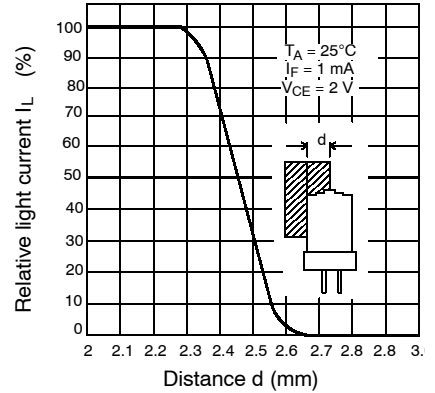
**Engineering Data**  
Temperature Characteristics



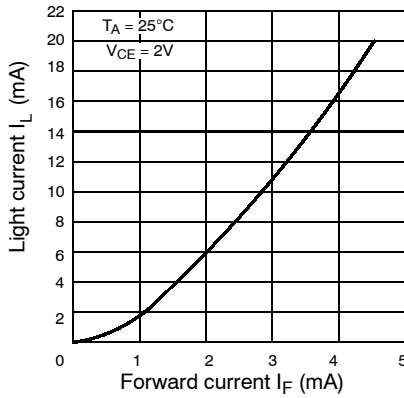
Input Characteristics (Typical)



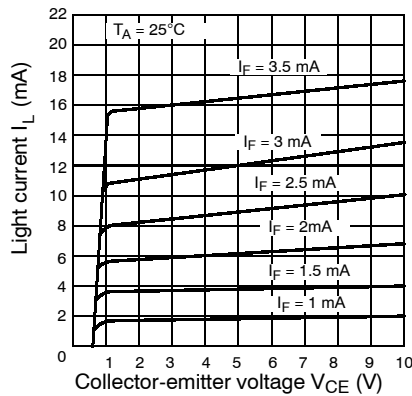
Sensing Position Characteristics (Typical)



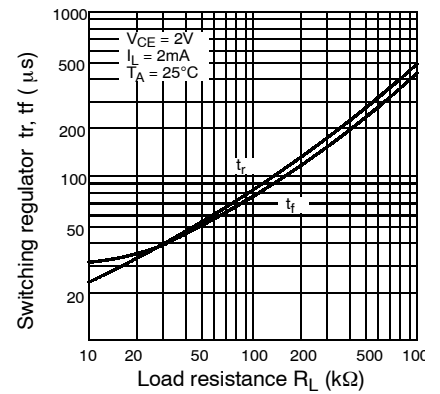
Input/output Characteristics (Typical)



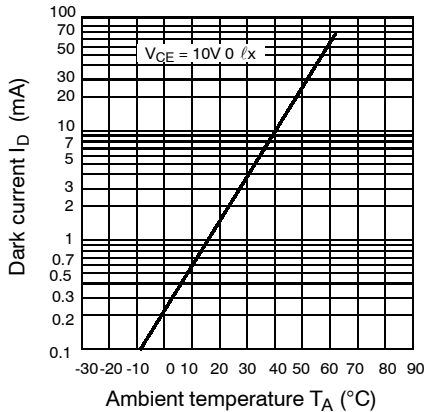
Output Characteristics (Typical)



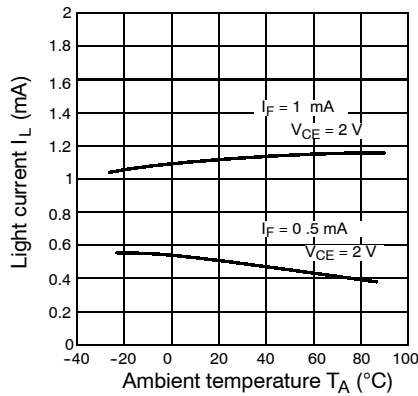
Response Time vs Load Resistance Characteristics (Typical)



Dark Current Temperature Dependency (Typical)



Light Current Temperature Dependency (Typical)



**NOTE: DIMENSIONS SHOWN ARE IN MILLIMETERS. To convert millimeters to inches divide by 25.4.**

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